



SOD-323 Plastic-Encapsulate ESD Protection Diodes

DESCRIPTION

The ESD3B5CM is designed to protect voltage sensitive components from ESD and transient voltage events. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium. Because of its small size, it is suited for use in cellular phones, portable devices, digital cameras, power supplies and many other portable applications where board space comes at a premium. Also because of its low capacitance, it is suited for use in high frequency designs such as USB 2.0 high speed, VGA, DVI, SDI and other high speed line applications.

This device has been specifically designed to protect sensitive components which are connected to data and transmission lines from overvoltage caused by ESD(electrostatic discharge), and EFT (electrical fast transients).

Features

- ◆ Peak power dissipation: 500W (8/20µs)
- ◆ IEC61000-4-2 (ESD) ±30kV (air), ±30kV (contact)
- ◆ IEC61000-4-4 (EFT) 40A (5/50ns)
- ◆ Protects one directional I/O line
- Low clamping voltage
- Low leakage current
- Low capacitance
- Working voltages: 5V
- Meets MSL 1 Requirements

Applications

- ♦ High Speed Line :USB1.0/2.0, VGA, DVI, SDI
- Serial and Parallel Ports
- Notebooks, Desktops, Servers
- Projection TV
- Cellular handsets and accessories
- Portable instrumentation
- Peripherals

Pin Configuration





Circuit Diagram



Mechanical Characteristics

◆ Package: SOD-323

◆ Flammability Rating: UL 94V-0

◆ Terminals: Gold plated, solderable per MIL-STD-750, method 2026

Packaging: Tape and Reel

Marking: 5/9

Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit	
ESD per IEC 61000-4-2 (Air)	\/505	± 30	KV	
ESD per IEC 61000-4-2 (Contact)	VESD	± 30		
Peak Pulse Power(8/20us)	P _{PP}	500	W	
Operating Temperature	T _{OPT}	−55 to +150	°C	
Storage Temperature	Tstg	−55 to +150	°C	

The above data are for reference only.

DN:T21824A1





Low Capacitance Bidirectional TVS/ESD Protection Diode

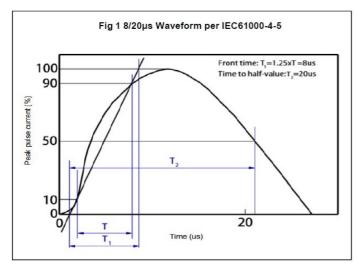
Electrical Characteristics (TA=25°C unless otherwise specified)

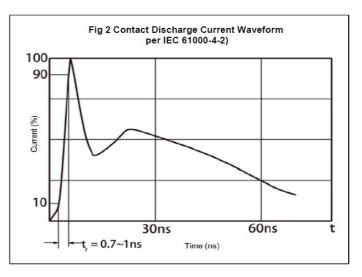
Symbol	Parameter	Test Condition	Min	Тур	Max	Units
V_{RWM}	Reverse Working Voltage				5.0	V
V_{BR}	Reverse Breakdown Voltage	I _T = 1mA	5.8		7.8	V
I _R	Reverse Leakage Current	V _{RWM} = 5V			1.0	μΑ
V _C	Clamping Voltage	$I_{PP} = 1A, t_p = 8/20 \mu s$			9.8	V
V _C	Clamping Voltage	I_{PP} = 25A, t_p = 8/20 μ s		15	20	V
CJ	Junction Capacitance	V _R = 0V, f = 1MHz		33	40	pF

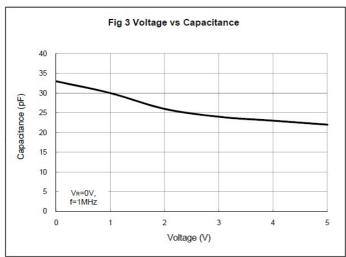
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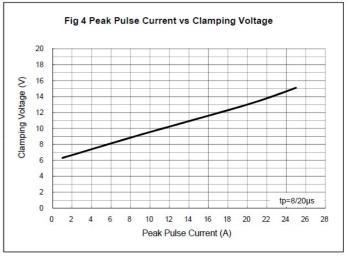


ELECTRICAL CHARACTERISTICS CURVE









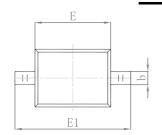
The curve above is for reference only.

http://www.microdiode.com Rev:2021A1 Page :3

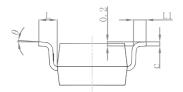
Low Capacitance Bidirectional TVS/ESD Protection Diode

Outlitne Drawing

SOD-323 Package Outline Dimensions

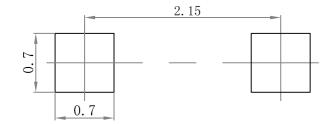






Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A		1.000		0.039	
A1	0.000	0.100	0.000	0.004	
A2	0.800	0.900	0.031	0.035	
b	0.250	0.350	0.010	0.014	
С	0.080	0.150	0.003	0.006	
D	1.200	1.400	0.047	0.055	
E	1.600	1.800	0.063	0.071	
E1	2.550	2.750	0.100	0.108	
L	0.475 REF.		0.019 REF.		
L1	0.250	0.400	0.010	0.016	
θ	0°	8°	0°	8°	

Suggested Pad Layout



Note:

- 1. Controlling dimension: in/millimeters.
- 2.General tolerance: ±0.05mm.
- 3. The pad layout is for reference purposes only.

PACKAGE SPECIFICATIONS

Package	Reel Size	Reel DIA. (mm)	Q'TY/Reel (pcs)	Box Size (mm)	QTY/Box (pcs)	Carton Size (mm)	Q'TY/Carton (pcs)
SOD-323	7'	178	3000	183×188×80	45,000	386×265×215	180,000

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